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CDCV304

SCAS643I-SEPTEMBER 2000-REVISED OCTOBER 2017

CDCV304 200-MHz General-Purpose Clock Buffer, PCI-X Compliant

1 Features

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INSTRUMENTS

- General-Purpose and PCI-X 1:4 Clock Buffer
- **Operating Frequency** .
 - 0 MHz to 200 MHz General-Purpose
- Low Output Skew: <100 ps
- Distributes One Clock Input to One Bank of Four • Outputs
- Output Enable Control that Drives Outputs Low ٠ when OE is Low
- Operates from Single 3.3-V Supply or 2.5-V • Supply
- **PCI-X** Compliant
- 8-Pin TSSOP Package

2 Description

The CDCV304 is a high-performance, low-skew, general-purpose PCI-X compliant clock buffer. It distributes one input clock signal (CLKIN) to the output clocks (1Y[0:3]). It is specifically designed for use with PCI-X applications. The CDCV304 operates at 3.3 V and 2.5 V and is therefore compliant to the 3.3-V PCI-X specifications.

Support &

Community

20

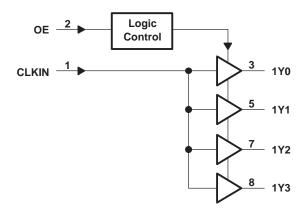
The CDCV304 is characterized for operation from -40°C to 85°C for automotive and industrial applications.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
CDCV304	TSSOP (8)	3.00 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Functional Block Diagram





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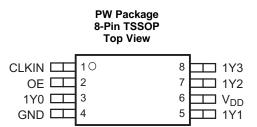
3 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision H (February 2011) to Revision I	Page
Changed datasheet layout	1
 Added Junction temperature, T_{j, max}125 °C 	
Changes from Revision G (January 2011) to Revision H	Page
Added missing characteristics graphs.	
Changes from Revision F (April 2009) to Revision G	Page
• Added ψ_{JT} and ψ_{JB} specs to the Thermal Information Table and changed $R_{\theta JB}$ and $R_{\theta JC}$ respectively.	



4 Pin Configuration and Functions



Pin Functions

	PIN	I/O	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
1Y[0:3]	3, 5, 7, 8	0	Buffered output clocks
CLKIN	1	I	Input reference frequency
GND	4	Power	Ground
OE	2	I	Output enable control
V _{DD}	6	Power	Supply

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

	MIN	MAX	UNIT
Supply voltage range, V _{DD}	-0.5	4.3	V
Input voltage range, V ₁ ^{(2) (3)}	-0.5	V _{DD} + 0.5	V
Output voltage range, $V_0^{(2)}$ (3)	-0.5	V _{DD} + 0.5	V
Input clamp current, I_{IK} (V _I < 0 or V _I > V _{DD})	-50	50	mA
Output clamp current, I_{OK} (V _O < 0 or V _O > V _{DD})	-50	50	mA
Continuous total output current, $I_O (V_O = 0 \text{ to } V_{DD})$	-50	50	mA
Package thermal impedance, θ_{JA} : PW package		230.5	°C/W
Junction temperature, T _{j, max}		125	°C
Storage temperature range T _{stg}	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(3) This value is limited to 4.6 V maximum.

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5.2 Recommended Operating Conditions

		MIN	NOM MA	X UNIT
Supply voltage, V _{DD}		2.3	3	6 V
Low-level input voltage, V _{IL}			0.3 x V _I	D V
High-level input voltage, V _{IH}		0.7 x V _{DD}		V
Input voltage, V _I		0	V	D V
High lovel output ourrest	V _{DD} = 2.5 V		-^	2 mA
High-level input voltage, V_{IH} Input voltage, V_I High-level output current, I_{OH} V_{D} Low-level output current, I_{OL}	V _{DD} = 3.3 V		-2	4
	V _{DD} = 2.5 V			2
Low-level output current, I _{OL}	V _{DD} = 3.3 V		2	mA
Operating free-air temperature, T,	A	-40	8	5 °C

5.3 Thermal Information

				CDCV304	
	THERMAL METRIC ⁽¹⁾		THERMAL AIR FLOW (CFM)	PW (TSSOP)	UNIT
				8 PINS	
			0	149	
			150	142	
		High K	250	138	- - - - - - - - - - - - - - - - - - -
D lunatio			500	132	
R_{\thetaJA}	Junction-to-ambient thermal resistance			230	
		Law K		185	
		Low K		170	
				150	
R _{0JC(top)}	R _{0JB} Junction-to-board thermal resistance			43.7	
$R_{\theta JB}$				102	
ΨJT				1.8	
ΨЈВ	Junction-to-board characterization parameter			100.2	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CC	NDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT	
V _{IK}	Input voltage	V _{DD} = 3 V,	I _I = -18 mA			-1.2	V	
		V _{DD} = 2.3 V,	I _{OH} = -8 mA	1.8				
		V _{DD} = 2.3 V,	I _{OH} = -16 mA	1.5				
V _{ОН}	High-level output voltage	V_{DD} = min to max,	I _{OH} = -1 mA	V _{DD} - 0.2			V	
		V _{DD} = 3 V,	I _{OH} = -24 mA	2				
		V _{DD} = 3 V,	I _{OH} = -12 mA	2.4				
		V _{DD} = 2.3 V,	$I_{OL} = 8 \text{ mA}$			0.5		
		V _{DD} = 2.3 V,	I _{OL} = 16 mA			0.7		
V _{OL}	Low-level output voltage	V_{DD} = min to max,	I _{OL} = 1 mA			0.2	V	
		V _{DD} = 3 V,	$I_{OL} = 24 \text{ mA}$			0.8		
		V _{DD} = 3 V,	I _{OL} = 12 mA			0.55		
	High lovel output ourrest	V _{DD} = 3 V,	$V_{O} = 1 V$	-50			٣٨	
I _{OH} H	High-level output current	V _{DD} = 3.3 V,	V _O = 1.65 V		-55		mA	
1		V _{DD} = 3 V,	$V_0 = 2 V$	60			m ^	
I _{OL}	Low-level output current	V _{DD} = 3.3 V,	V _O = 1.65 V		70		mA	

(1) All typical values are with respect to nominal V_{DD} and $T_A = 25^{\circ}C$.

Electrical Characteristics (continued)

PARAMETER		TEST C	MIN	TYP ⁽¹⁾	MAX	UNIT		
I _I	Input current	$V_I = V_O \text{ or } V_{DD}$				±5	μA	
I _{DD}	Dynamic current, see Figure 1	f = 67 MHz,	$V_{DD} = 2.7 V$			28		
		f = 67 MHz,	V _{DD} = 3.6 V			37	mA	
CI	Input capacitance	V _{DD} = 3.3 V,	$V_I = 0 V \text{ or } V_{DD}$		3		pF	
Co	Output capacitance	V _{DD} = 3.3 V,	$V_I = 0 V \text{ or } V_{DD}$		3.2		pF	

over recommended operating free-air temperature range (unless otherwise noted)

5.5 Timing Requirements

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f _{clk}	Clock frequency		0		200	MHz

5.6 Switching Characteristics: $V_{DD} = 2.5 V \pm 10\%$

 $V_{DD} = 2.5 \text{ V} \pm 10\%$, $C_L = 10 \text{ pF}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{PLH}	Low-to-high propagation delay	See Figure 4 and Figure 5	2	2.9	4.5	20
t _{PHL}	High-to-low propagation delay		2	3	4.5	ns
t _{sk(o)}	Output skew ⁽²⁾	See Figure 6		50	150	ps
t _r	Output rise slew rate		1.5	2.2	4	V/ns
t _f	Output fall slew rate		1.5	2.2	4	V/ns

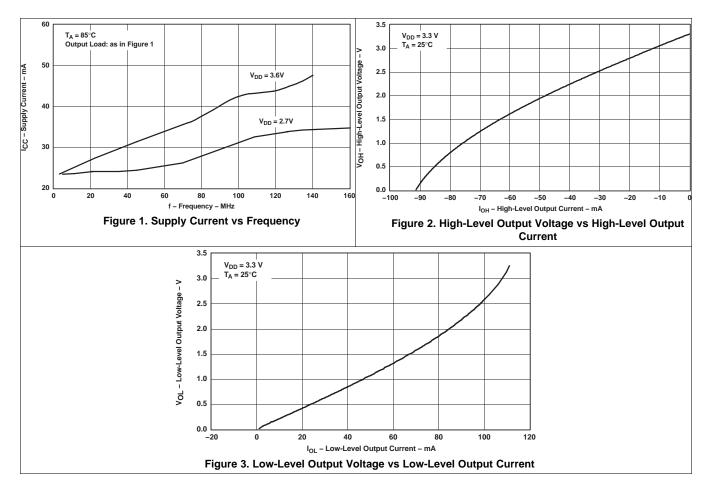
5.7 Switching Characteristics: $V_{DD} = 3.3 \text{ V} \pm 10\%$

 V_{DD} = 3.3 V ± 10%, C_L= 10 pF (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{PLH}	Low-to-high propagation delay	See Figure 4 and Figure F	1.8	2.4	3	~~
t _{PHL}	High-to-low propagation delay		1.8	2.5	3	ns
t _{sk(o)}	Output skew ⁽²⁾			50	100	ps
		12 kHz to 5 MHz, f_{out} = 30.72 MHz		63		(
t _{jitter} Additive phase jitter	Additive phase jitter from input to output 1Y0	12 kHz to 20 MHz, f _{out} = 125 MHz	56		fs rms	
t _{sk(p)}	Pulse skew	$V_{IH} = V_{DD}, V_{IL} = 0 V$			150	ps
t _{sk(pr)}	Process skew			0.2	0.3	ns
t _{sk(pp)}	Part-to-part skew			0.25	0.4	ns
	Clash kinh ting and Figure 7	66 MHz	6			
t _{high}	Clock high time, see Figure 7	140 MHz	3			ns
		66 MHz	6	6		
t _{low}	Clock low time, see Figure 7	140 MHz	3			ns
t _r	Output rise slew rate ⁽³⁾	$V_0 = 0.4 V$ to 2 V	1.5	2.7	4	V/ns
t _f	Output fall slew rate ⁽³⁾	$V_0 = 2 V \text{ to } 0.4 V$	1.5	2.7	4	V/ns

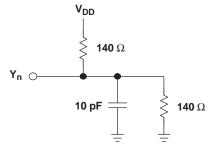


5.8 Typical Characteristics





6 Parameter Measurement Information





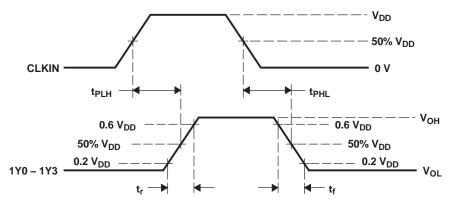
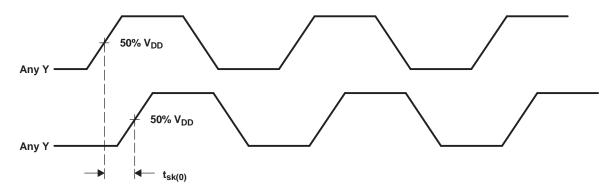


Figure 5. Voltage Waveforms Propagation Delay (tpd) Measurements





			← t _{cyc} →
PARAMETER	VALUE	UNIT	thigh
V _{IH(Min)}	0.5 V _{DD}	v	
V _{IL(Max)}	0.35 V _{DD}	v	
V _{test}	0.4 V _{DD}	v	$V_{\text{test}} $
			V _{IL(Max)} 0.2 V _{DD}
			0.4 V _{DD}

Peak to Peak (Minimum)

A. All parameters in Figure 7 are according to PCI-X 1.0 specifications.

Figure 7. Clock Waveform

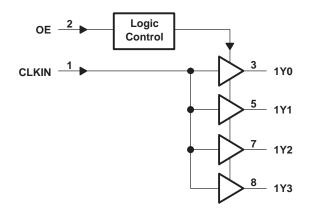
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7 Detailed Description

7.1 Functional Block Diagram



7.2 Device Functional Modes

INP	OUTPUTS	
CLKIN	OE	1Y[0:3]
L	L	L
Н	L	L
L	Н	L
Н	Н	Н



8 Device and Documentation Support

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

8.3 Trademarks

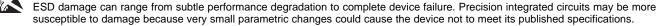
E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.



8.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
CDCV304PW	Active	Production	TSSOP (PW) 8	150 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304
CDCV304PW.A	Active	Production	TSSOP (PW) 8	150 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304
CDCV304PWG4	Active	Production	TSSOP (PW) 8	150 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304
CDCV304PWR	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304
CDCV304PWR.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304
CDCV304PWRG4	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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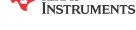


OTHER QUALIFIED VERSIONS OF CDCV304 :

• Enhanced Product : CDCV304-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

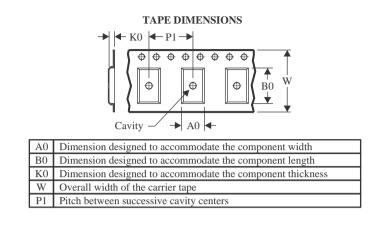


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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	0	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDCV304PWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

24-Jul-2025



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CDCV304PWR	TSSOP	PW	8	2000	353.0	353.0	32.0

TEXAS INSTRUMENTS

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24-Jul-2025

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
CDCV304PW	PW	TSSOP	8	150	530	10.2	3600	3.5
CDCV304PW.A	PW	TSSOP	8	150	530	10.2	3600	3.5
CDCV304PWG4	PW	TSSOP	8	150	530	10.2	3600	3.5

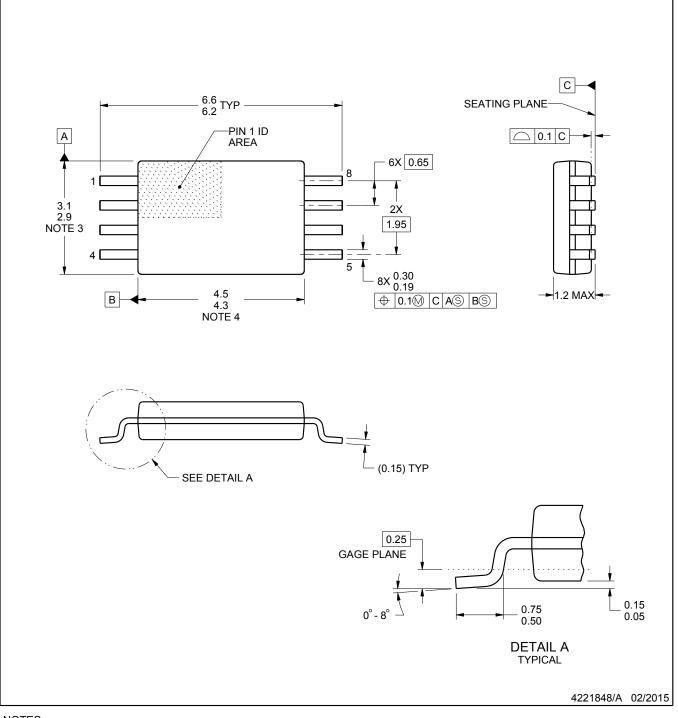
PW0008A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.

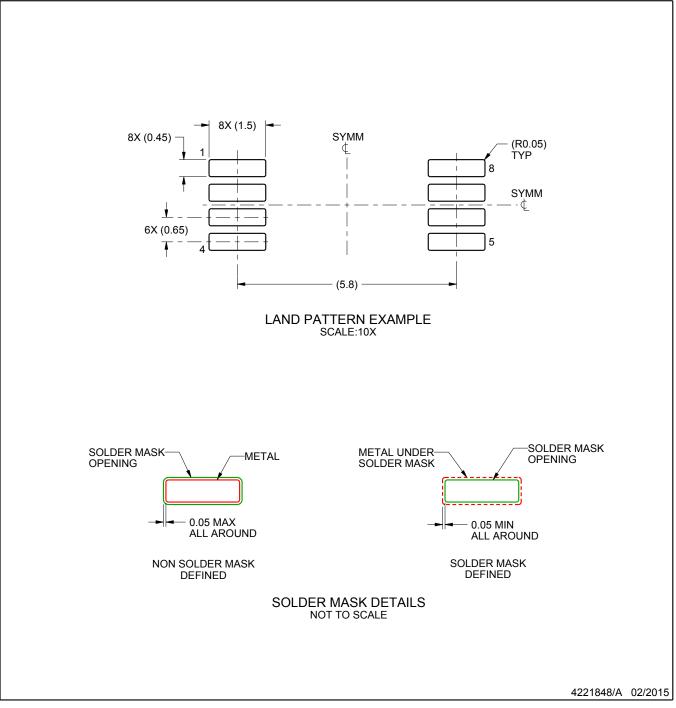


PW0008A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0008A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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